# **CETC** 中电国基南方集团有限公司

# WS3A004065E Silicon Carbide Schottky Diode

Features
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- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V<sub>F</sub>
- Temperature-independent Switching
- 175°C Operating Junction Temperature

#### **Benefits**

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

### Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

V <sub>RRM</sub>	=	650	V
I <sub>F</sub> ( T <sub>C</sub> ≤135℃)	=	6	А
Qc	=	9	nC

#### Package





Part Number	Package	Marking	
WS3A004065E	TO-252	WS3A004065E	

#### **Maximum Ratings**

Symbol	Parameter	Value	Unit	Test Conditions	Note
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	650	V	$T_{C} = 25^{\circ}C$	
V <sub>RSM</sub>	Surge Peak Reverse Voltage	650	V	$T_{C} = 25^{\circ}C$	
V <sub>R</sub>	DC Blocking Voltage	650	V	$T_{C} = 25^{\circ}C$	
l <sub>F</sub>	Forward Current	13 6 4	A	T <sub>C</sub> ≤ 25°C T <sub>C</sub> ≤ 135°C T <sub>C</sub> ≤ 155°C	
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current	40	А	$T_C = 25^{\circ}C$ , $t_p = 8.3$ ms, Half Sine Wave	
P <sub>tot</sub>	Power Dissipation	51	W	$T_{C} = 25^{\circ}C$	Fig.3
Tc	Maximum Case Temperature	155	°C		
T <sub>J</sub> ,T <sub>STG</sub>	Operating Junction and Storage Temperature	-55 to 175	°C		



## **Electrical Characteristics**

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note	
N		1.4	1.65	V	$I_F = 4A, T_J = 25^{\circ}C$		
V <sub>F</sub>	Forward Voltage	1.7	2.3	V	$I_F = 4A, T_J = 175^{\circ}C$	Fig.1	
	Devenes Orment	1	10		$V_{R} = 650V, T_{J} = 25^{\circ}C$	E a O	
I <sub>R</sub>	Reverse Current	5	100 <sup>µA</sup>	μΑ	$V_{R} = 650V, T_{J} = 175^{\circ}C$	Fig.2	
		230			$V_R = 0V, T_J = 25^{\circ}C, f = 1MHz$		
С	Total Capacitance	24	/	pF	$V_R = 200V, T_J = 25^{\circ}C, f = 1MHz$	Fig.5	
		20			$V_R = 400V, T_J = 25^{\circ}C, f = 1MHz$		
	Total Capacitive Charge	9	,		$V_{R} = 650V, I_{F} = 4A$	<b>F</b> : 4	
Q <sub>C</sub>			/	nC	di/dt = 200A/ $\mu$ s, T <sub>J</sub> = 25 $^{\circ}$ C	Fig.4	

### **Thermal Characteristics**

Symbol	Parameter	Тур.	Unit	Note
R <sub>θJC</sub>	Thermal Resistance from Junction to Case	2.9	°CW	Fig.6
R <sub>0JA</sub>	R <sub>8JA</sub> Thermal Resistance from Junction to Ambient		°CW	
T <sub>sold</sub>	T <sub>sold</sub> Soldering Temperature		°C	

# **Typical Performance**

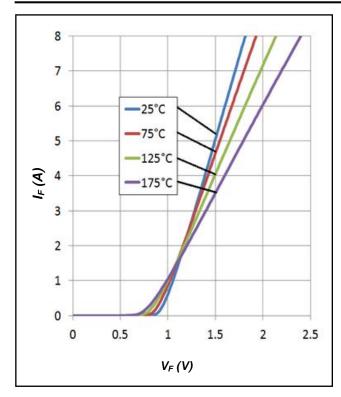
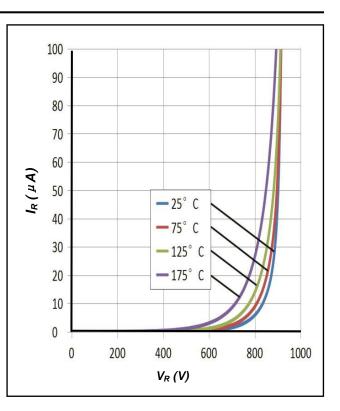


Figure 1. Forward Characteristics



#### Figure 2. Reverse Characteristics



# **Typical Performance**

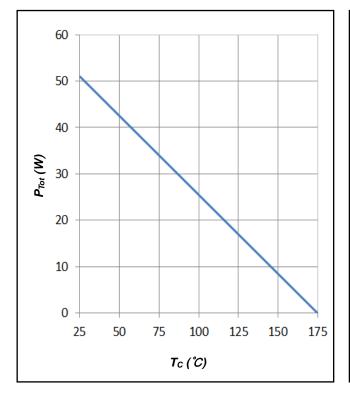


Figure 3. Power Derating

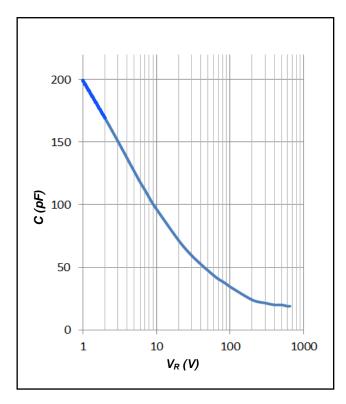


Figure 5. Total Capacitance vs. Reverse Voltage

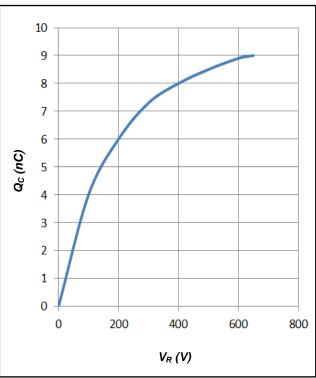
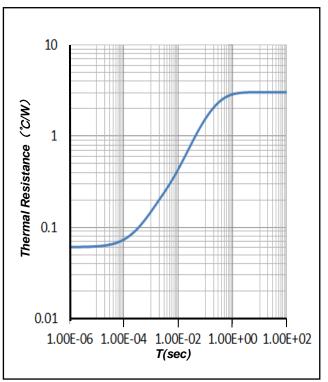
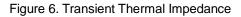


Figure 4. Total Capacitive Charge vs. Reverse Voltage

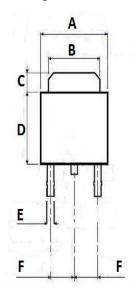




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# **Package Dimensions**

Package TO-252

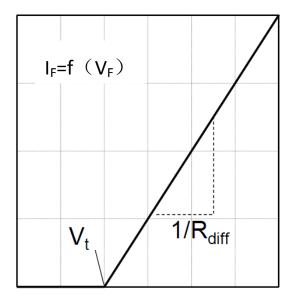


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Γ	Symbol	Min. (mm)	Typ. (mm)	Max. (mm)				
Ī	А	6.3	6.5	6.7				
Ī	В	5.2	5.3	5.4				
Ī	С	1.15	1.25	1.35				
Ī	D	5.7	5.9	6.1				
Ī	E	0.65	0.7	0.75				
	F	2.1	2.3	2.5				
Ī	G	2.2	2.3	2.4				
ſ	Н	1.45	1.5	1.55				
Ī	l	2.9	3.0	3.1				
Ī	J	0.45	0.5	0.55				
	К	0.9	1	1.1				

## **Simplified Diode Model**

#### Equivalent IV Curve for Model



#### **Mathematical Equation**

$$V_F = V_t + I_F \times R_{diff}$$

$$V_{t} = -0.0011 \times T_{j} + 0.99 [V]$$
  
R<sub>diff</sub> = 1.83×10<sup>-6</sup>×T<sub>j</sub><sup>2</sup> + 2.52×10<sup>-4</sup>×T<sub>j</sub> + 0.099 [Ω]

Note:

 $\label{eq:time_state} \begin{array}{l} Tj = Diode \mbox{ Junction Temperature In Degrees Celsius,} \\ \mbox{valid from 25°C to 175°C} \\ I_{F} = \mbox{ Forward Current} \\ \mbox{ Less than 8A} \end{array}$ 

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